

## APPLICATION DATA SHEET

### APPLICATION INFORMATION

Application Type::	REGULAR
Subject Matter::	UTILITY
CD-ROM or CD-R?::	NONE
Title::	METHOD OF MANUFACTURING SEMICONDUCTOR DEVICE CAPABLE OF SUPPRESSING IMPURITY CONCENTRATION REDUCTION IN DOPED CHANNEL REGION ARISING FROM FORMATION OF GATE INSULATING FILM
Attorney Docket Number::	246378US2
Total Drawing Sheets::	33

### INVENTOR INFORMATION

Applicant Authority Type::	INVENTOR
Primary Citizenship Country::	Japan
Status::	FULL CAPACITY
Given Name::	Yoshinori
Family Name::	TANAKA
City of Residence::	Tokyo
Country of Residence::	Japan
Street of Mailing Address::	c/o Renesas Technology Corp., 4-1, Marunouchi 2-chome, Chiyoda-ku,
City of Mailing Address::	Tokyo
Country of Mailing Address::	Japan

Applicant Authority Type:: INVENTOR  
Primary Citizenship Country:: Japan  
Status:: FULL CAPACITY  
Given Name:: Katsuyuki  
Family Name:: HORITA  
City of Residence:: Tokyo  
Country of Residence:: Japan  
Street of Mailing Address:: c/o Renesas Technology Corp., 4-1,  
Marunouchi 2-chome, Chiyoda-ku,  
City of Mailing Address:: Tokyo  
Country of Mailing Address:: Japan

Applicant Authority Type:: INVENTOR  
Primary Citizenship Country:: Japan  
Status:: FULL CAPACITY  
Given Name:: Heiji  
Family Name:: KOBAYASHI  
City of Residence:: Tokyo  
Country of Residence:: Japan  
Street of Mailing Address:: c/o Renesas Technology Corp., 4-1,  
Marunouchi 2-chome, Chiyoda-ku,  
City of Mailing Address:: Tokyo  
Country of Mailing Address:: Japan

#### CORRESPONDENCE INFORMATION

Correspondence Customer Number:: 22850

#### REPRESENTATIVE INFORMATION

Representative Customer Number:: 22850

#### FOREIGN PRIORITY INFORMATION

Application Number:	Country::	Filing Date::	Priority Claimed::
2003-143438	Japan	05/21/03	YES

#### ASSIGNMENT INFORMATION

Assignee Name:: Renesas Technology Corp.

Street of Mailing Address::

4-1, Marunouchi 2-chome,  
Chiyoda-ku

City of Mailing Address::

TOKYO

Country of Mailing Address::

JAPAN